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A constitutive model coupling irradiation with two-phase lithiation for lithium-ion battery electrodes

Hui Wu[a*], Zhoucan Xie[b*], Yan Wang[c], Panpan Zhang[a,d], Lizhong Sun[a], Chunsheng Lu[d] and Zengsheng Ma[a]

[a]National−Provincial Laboratory of Special Function Thin Film Materials, and School of Materials Science and Engineering, Xiangtan University, Hunan, People's Republic of China; [b]State Key Laboratory of Nonlinear Mechanics, Institute of Mechanics, Chinese Academy of Science, Beijing, People's Republic of China; [c]School of Information and Electronic Engineering, Hunan University of Science and Technology, Hunan, People's Republic of China; [d]School of Civil and Mechanical Engineering, Curtin University, Perth, Western Australia, Australia

ABSTRACT

When lithium-ion batteries serve in extreme environments like space, severe irradiation might induce significant decay of the electrochemical performances and mechanical properties. In this paper, an electrochemical-irradiated constitutive model is proposed to explore the evolution of dislocation, defect and stress in electrodes during a two-phase lithiation process. The results from the analytic formulation and finite difference calculations show that, as Li intercalation proceeding, the hoop stress in the surface of a spherical particle converts from compression into tension because the large lithiation strain and plastic yielding at the front pushes out the material behind it. And the plastic flow resistance continuously increases with increasing irradiation dose result from the impediment of a defect to dislocation glide. There is a clear peak in the distribution of stress at yielding locations due to the competition between dislocations multiplication and defects annihilation. The model is meaningful for thoroughly understanding the micro-mechanism of lithiation deformation and provides a guideline for predicting their mechanical behaviours of lithium-ion batteries in unconventional environment.

1. Introduction

Although they have been widely used as power devices for portable electronics, high performance lithium-ion batteries (LIBs) are still in great need [1]. Electrode materials such as Si, Ge and Sn with extremely a high theoretical specific capacity are a potential substitution of conventional graphite.

However, a serious obstruction to their commercial use is the large volume deformation (~400% in full lithiation of Si), resulting in fast capacity loss, short life, instability and even failure [2–11]. Thus, it is necessary to clarify the generation and evolution of diffusion-induced stress during lithiation of electrode materials.

Based on available experiments, plastic deformation appears in high-capacity electrode materials during lithiation [7,9,12–18]. For example, by using a multi-beam optical sensor technique, it is shown that the Si thin-film electrode undergoes repeated compressive and tensile-plastic flow during intercalation and deintercalation of Li, and dissipates the mechanical energy [12]. With the help of in situ transmission electron microscopy, a sharp interface (~1 nm thickness) was observed between the pristine Si and lithiated amorphous Li_xSi ($x = 3.75$) phase during lithiation of single crystal silicon [19], together with a large Li concentration gradient at the two-phase boundary [20]. Such a sharp interface can result in an abrupt change of Li concentrations across the phase boundary, leading to a sudden transformation from compression to tension of diffusion-induced stress [21].

Recently, several trans-scale theoretical models were also established to describe the deformation behaviour of electrode materials during charging and discharging [22–24]. For instance, an elasto-plastic non-linear two-phase lithiation model was proposed to obtain the dynamic evolution of Li-ion concentration and diffusion-induced stress [22,23,25]. Besides, the plasticity origin of Si electrodes was simulated by first-principles calculation [26]. A framework of mechanics was presented for a physical understanding of stress generation during lithiation of high-capacity electrode materials [27]. Zuo et al. built up a phase field model for lithium diffusion, finite deformation, stress evolution and crack propagation in LIBs [27]. The effects of particle shape and concurrent plasticity on stress generation during lithiation were studied in particulate LIB electrodes. These models can well explain diffusion-induced stress and fracture behaviours due to the electrochemical reaction under regular environments.

During deep space exploration, however, LIBs suffer severe irradiation effects, high radiation field and post-nuclear accident scenario [28–32]. Qiu et al. [33] and Samin et al. [34] characterised the surface morphologies of cathode materials before and after neutron and gamma-ray irradiation with a growing particle size and reported that irradiation causes disordering of crystal structures in a post-irradiation sample, which further results in capacity loss of batteries. Deterioration was detected because of the irradiation effect on electrode and electrolyte materials [32]. Recently, Ma et al. [35] developed an electrochemical-irradiated plasticity model to study the effects of irradiation and diffusion-induced stress on the mechanical properties of cylindrical electrodes, and showed that the yield strength of irradiated electrode materials increases with dose. The influence of irradiation on electrodes is due to the

change of microstructures [36–41]. For instance, a typical irradiation hardening phenomenon was observed in materials with a body-centered cubic structure (Cu) [42–44] and a face-centered cubic structure (Fe) [45–48]. A quantitative *in situ* nano-compression test was conducted to study the evolution of defect and dislocation of ion beam irradiated materials [49]. The electrochemical reaction dislocations in a single nanowire were continuously nucleated and absorbed at the moving reaction front [14], and irradiation defects were observed [50].

Unlike the models with only consideration of dislocation interaction (e.g. the Kocks-Mecking model) [51,52], the irradiation hardening model has been developed and used to describe the interaction between defect and dislocation [43,53]. Here, microscopic irradiation-induced defects and dislocations were introduced into a constitutive model that couples the irradiation hardening and two-phase interface in a nano-spherical particle [22,54–58].

In this paper, to explore the evolution of dislocations, defects and stress associated with a two-phase lithiation boundary, a constitutive model coupling irradiation with electrochemical reaction is established, which mainly involves the interaction between the electrochemical reaction dislocations and irradiation defects in a cathode particle of LIBs. The paper is organised as follows. Section 2 represents a theoretical framework that takes into account the general elasto-plastic lithiation deformation of associated with two-phase boundary and the plastic correction based on an irradiation hardening model. Then, in Section 3, numerical results of the evolution of defects, dislocation density and stress are analysed. Finally, conclusions are given in Section 4.

2. Theoretical framework

2.1. A general mechanical constitutive model

Since a large volume swelling due to insertion of Li-ions is accommodated by the elasto-plastic deformation in lithiated electrode particles, the total strain rate $\dot{\varepsilon}_{ij}$ can be written as

$$\dot{\varepsilon}_{ij} = \dot{\varepsilon}_{ij}^e + \dot{\varepsilon}_{ij}^p + \dot{\varepsilon}_{ij}^c, \tag{1}$$

where $\dot{\varepsilon}_{ij}^e$ and $\dot{\varepsilon}_{ij}^p$ are elastic and plastic strain rates, respectively. $\dot{\varepsilon}_{ij}^c$ is the chemical strain rate caused by Li insertion that is proportional to the rate of normalised Li concentration $\dot{c}$, that is

$$\dot{\varepsilon}_{ij}^c = \beta \dot{c} \delta_{ij}, \tag{2}$$

where $\beta = (\Omega^{\text{lithiated}}/\Omega^{\text{SnO}_2})$ is a volume expansion coefficient of electrode particles, Ω^{SnO_2} is the volume of SnO_2 atom, and $\Omega^{\text{lithiated}}$ represents the volume of lithiated part. c ranging from 0 to 1 is the Li-ion concentration normalised at the maximum Li-ion concentration c_0 (the full lithium state). δ_{ij} is the

Kronecker delta. According to Hooke's law, the elastic strain rate $\dot{\varepsilon}_{ij}^e$ can be represented as

$$\dot{\varepsilon}_{ij}^e = \frac{1}{E}[(1+v)\dot{\sigma}_{ij} - v\dot{\sigma}_{kk}\delta_{ij}], \tag{3}$$

where E and v are the elastic modulus and Poisson's radio. The plastic strain rate $\dot{\varepsilon}_{ij}^p$ complying with the J_2-flow theory of plasticity is proportion to the deviatoric stress $\sigma_{ij}' = \sigma_{ij} - \sigma_{kk}\delta_{ij}/3$, namely

$$\dot{\varepsilon}_{ij}^p = \frac{3\dot{\varepsilon}^p}{2\sigma_e}\sigma_{ij}'. \tag{4}$$

As the von Mises effective stress $\sigma_e = \sqrt{3\sigma_{ij}'\sigma_{ij}'/2}$ is equal to the yield stress, $\dot{\varepsilon}^p = \sqrt{(2/3)\dot{\varepsilon}_{ij}^p\dot{\varepsilon}_{ij}^p}$ refers to the plastic strain rate.

2.2. Yield function

In irradiation environments, the mechanical properties of materials are affected by the coupling of dislocation and defect. Based on previous studies [20,59], the slip shear stress τ_y is associated with dislocations and defect densities. For a single crystal, a rate-independent yield function, $F(\sigma, \tau_y)$ [14,26,28–32,36,60] can be written as

$$F(\sigma, \tau_y) = \sigma_e - \tau_y, \tag{5}$$

where the total shear strain τ_y on a slip plane is given in terms of the total microstructures density ρ_t by Franciosi and Zaoui [61]

$$\tau_y = \eta Gb\sqrt{\sum_t^N K_t\rho_t} = \eta Gb\sqrt{K\rho_d + L\rho_f}, \tag{6}$$

where η is a statistical parameter [62], G is the shear modulus, b is Burger's vector, K_t is an interaction coefficient of microstructures, and ρ_d is the density of dislocations. The density of defect ρ_f can be calculated by

$$\rho_f = N_f d_f. \tag{7}$$

Correspondingly, K is the dislocation coefficient related to the slip systems and L is the defect coefficient representing the interaction between dislocations and defects [63]. N_f is the number density and d_f is the average size of stacking fault tetrahedrons (SFTs). Thus, $F(\sigma, \tau_y)$ can be expressed as

$$F(\sigma, \tau_y) = \sigma_e - \eta Gb\sqrt{K\rho_d + L\rho_f}. \tag{8}$$

The plastic deformation of a metal is realised through the dislocation slip inside grains. The generation of dislocations is based on the resistance to dislocation

movement posed by forest dislocations acting as random obstacles. That is, the expansion of dislocation loops origins from the Frank-Read type sources. The mutual annihilation between parallel dislocations with the same character but the opposite sign is assumed to be the predominant annihilation mechanism. Thus, the evolution of dislocations is controlled by the growth and dynamic annihilated terms, namely,

$$\dot{\rho}_d = \frac{1}{b}\left(\frac{1}{S} - 2\rho_d y_c\right)|\dot{\varepsilon}^p|, \tag{9}$$

where y_c is the critical edge annihilation distance, and S represents the mean free path of dislocation segment that is related to the dislocation density,

$$S = \xi \rho_d^{-(1/2)}, \tag{10}$$

where ξ is a dimensionless proportionality constant controlling the mobility of dislocations.

According to molecular dynamics studies, the interaction of different dislocations with SFTs is rather complicated [64–67]. The defect clusters such as SFTs are annihilated by active dislocations or shrunk to a smaller size. The interaction between dislocations and defects may lead to a possible annihilation when SFTs are overlapped or truncated ∼70‒80% of defects [63]. As shown in Figure 1, the video-frame images exhibit the interaction between a truncated SFT and a dislocation, indicating that SFT2 was completely annihilated by moving dislocations [50]. Based on the schematic diagram of annihilation (see Figure 1), dislocations glide and then interact with SFTs on the glide plane, which could make the defect split up and transform into other types,

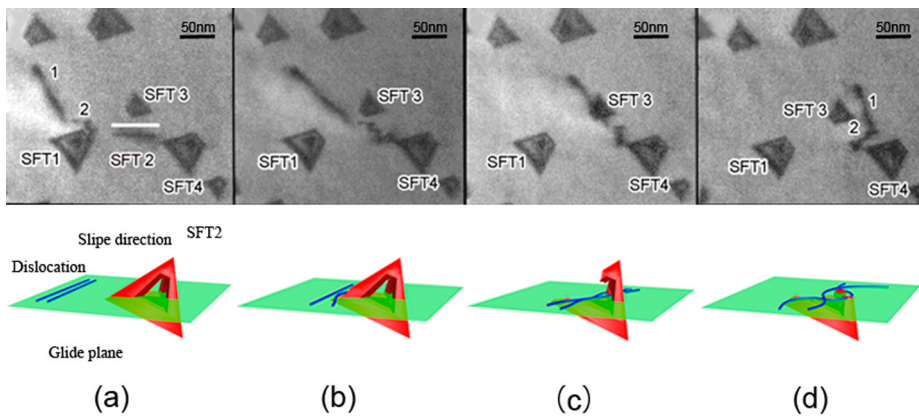**Figure 1.** Annihilation mechanism of defects: video-frame images showing the interaction between a truncated SFT and a dislocation, where SFT2 was completely annihilated by a moving dislocation. Snapshots were acquired at (a) 0 s, (b) 1.53 s, (c) 2.03 s, 3.97 and (d) 15.54 s (photographs are adapted from [50]); and the schematic diagram of interaction between dislocation and defect corresponding to the experiment upon.

such as a dislocation loop, and eventually being annihilated. The rate of defect annihilation $\dot{\rho}_f$ can be written as

$$\dot{\rho}_f = -A_s \rho_d (\rho_f - \rho_{fs}) \frac{d_f}{b} |\dot{\varepsilon}^p|, \qquad (11)$$

where A_s is the effective area of defect annihilation (see Figure 2), and

$$A_s = 2d_s S + \pi d_s^2, \qquad (12)$$

where a dislocation moves with the standoff distance d_s and S is the moving distance of a dislocation before it meets a defect in dt. ρ_{fs} is the steady-state value of defect density. In Equation (11), when $\rho_f - \rho_{fs} = 0$, the rate of defect annihilation is zero.

2.3. Elasto-plastic deformation during lithiation

In order to study the microstructural evolution during lithiation with irradiation, it is necessary to consider the migration of phase boundaries. Thus, a series of one-dimensional step-like profiles of Li-ion distribution with the flexible sigmoid function are assumed to simulate the movement of a sharp boundary between unlithiation and lithiation phases [26,68], viz.

$$\frac{c(r, t)}{c_0} = \frac{1}{1 + \exp[-\gamma(r - (R - kt)/R)]}, \qquad (13)$$

where $c(r, t)$ is the Li concentration at the location r and time t. c_0 is the concentration at a steady stage. Physically, the lithiation involves two processes: Li diffusion through the lithiated phase and the chemical reaction at the two-phase boundary. $\gamma = D/kR$ is the dimensionless parameters representing the relative rate of diffusion and reaction with a sharp profile of Li concentration jumping from 0 to 1, where D is the diffusivity of Li in a Li-rich phase, k is the rate at the front of reaction, and R is the particle size. The larger γ, the faster Li diffuses, implying that lithiation is limited by electrochemical reaction.
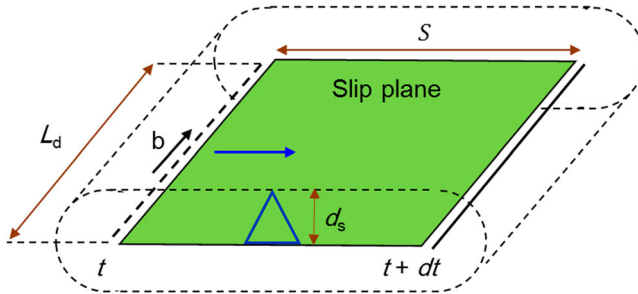

Figure 2. Schematic of dislocation glide with the standoff distance d_s between dislocations and SFTs, and the mean free path S of dislocations. Dislocations are expressed by solid lines and SFTs are shown as triangles.

It is important for two-phase lithiation to consider the effect of irradiated-defects evolution and stress generation on the rate at the reaction front. Some works have shown that the defects can make the initial Li insertion process thermodynamically more favourable [27]. Kim and Qi [69] described that the lithiation rate exhibits an exponential relationship with the vacancy concentration,

$$k \propto \exp\left[\frac{c_v * E_f}{k_B T}\right], \tag{14}$$

where c_v is the defect concentration at the two-phase boundary, E_f the defect formation energy, k_B the Boltzmann constant, and T the temperature.

On the other hand, the stress fields across the reaction front act as an energy barrier for lithiation reaction and hinder the movement of the reaction front [26]. The stress-induced energy barrier for lithiation reaction is given by

$$\Delta G = \Delta G_r - e\Phi + \Delta G_{\text{stress}} = \Delta G_r - e\Phi - \Omega\sigma_m. \tag{15}$$

where ΔG is the free energy of the lithiation reaction when both the stress and voltage are ignored. In the sign convention, a negative ΔG drives lithiation, and a negative value represents a larger driving force. The voltage contributes to the work $e\Phi$, where Φ and e are the voltage and elementary charge, respectively. When one lithium atom is incorporated into lithiated materials, the mean stress, σ_m, does the work $\Omega\sigma_m$, where Ω is the volume change caused by insertion of lithium atoms.

Thus, the reaction is taken to be thermally-activated by the kinetic model [26]

$$k = k_0 * \exp\left[\frac{c_v * E_f}{k_B T}\right] \exp\left[-\frac{\Delta G_r - \sigma_m\Omega}{k_B T}\right]. \tag{16}$$

here, k_0 is a parameter analogous to the exchange current density in a redox process.

In a spherical coordinate system $(r, \ \theta, \varphi)$ in Figure 3, it is assumed that $\dot{\varepsilon}_\theta = \dot{\varepsilon}_\varphi$, and the strain component can be written as

$$\begin{aligned} \dot{\varepsilon}_r &= \dot{\varepsilon}_r^e + \dot{\varepsilon}_r^p + \dot{\varepsilon}_r^c \\ \dot{\varepsilon}_\theta = \dot{\varepsilon}_\varphi &= \dot{\varepsilon}_\theta^e + \dot{\varepsilon}_\theta^p + \dot{\varepsilon}_\theta^c \end{aligned} \ . \tag{17}$$

Therefore, based on Equation (2), the chemical strain can be simplified as

$$\dot{\varepsilon}_r^c = \dot{\varepsilon}_\theta^c = \dot{\varepsilon}_\varphi^c = \beta\dot{c}. \tag{18}$$

Similarly, the elastic strain rate of Equation (3) is described as

$$\begin{aligned} \dot{\sigma}_r &= \frac{E}{(1-v)(1-2v)}[(1-v)\dot{\varepsilon}_r^e + 2v\dot{\varepsilon}_\theta^e] \\ \dot{\sigma}_\theta = \dot{\sigma}_\varphi &= \frac{E}{(1-v)(1-2v)}[\dot{\varepsilon}_\theta^e + v\dot{\varepsilon}_r^e] \end{aligned} \ . \tag{19}$$
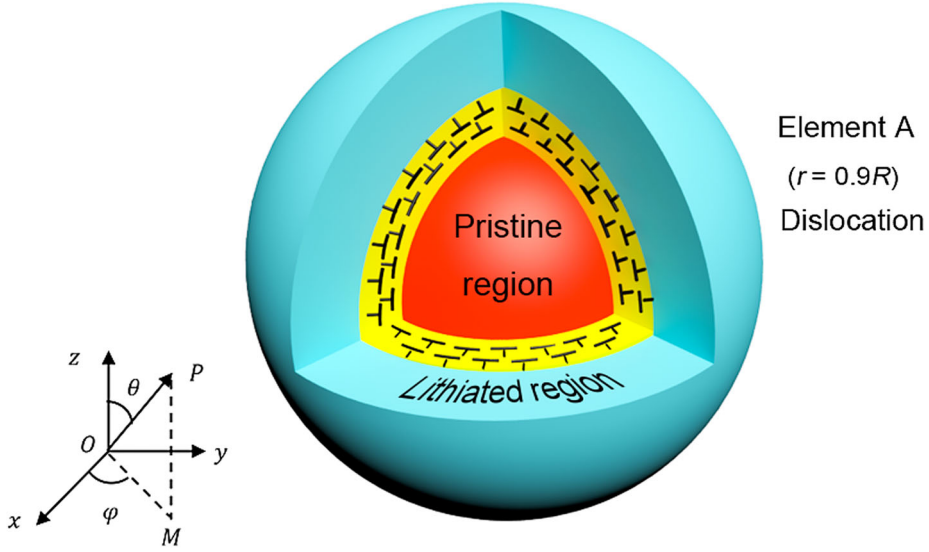
Figure 3. Schematic illustration of the two-phase mechanism for Li-ion diffusion and the element A located in $r / R = 0.9$.

The plastic strain rate of Equation (4) can be written as

$$\dot{\varepsilon}^p_r = \dot{\bar{\varepsilon}}^p \frac{3\sigma'_r}{2\sigma_e}$$
$$\dot{\varepsilon}^p_\theta = \dot{\varepsilon}^p_\varphi = \dot{\bar{\varepsilon}}^p \frac{3\sigma'_\theta}{2\sigma_e}, \tag{20}$$

and the deviatoric stresses are resolved by

$$\sigma'_r = \frac{1}{3}(\sigma_r - \sigma_\theta)$$
$$\sigma'_\theta = \sigma'_\varphi = \frac{1}{3}(\sigma_\theta - \sigma_r), \tag{21}$$

where the von Mises effective stress is

$$\sigma_e = \sqrt{\frac{3}{2}\sigma'_{ij}\sigma'_{ij}} = |\sigma_r - \sigma_\theta|. \tag{22}$$

To control the computation stabilisation with a sharp concentration boundary, the rate-dependence must have an asymptotic value. Thus, a power-exponential function was developed to express the equation the equivalent plastic strain [70,71], that is

$$\dot{\bar{\varepsilon}}^p = \dot{\varepsilon}^p_{eq}\left(\frac{\sigma_e}{\sigma_{flow}} - 1\right)^{\frac{1}{m}}\left(\frac{1}{1 + \exp\left[-80((\sigma_e/\sigma_{flow}) - 1)\right]}\right), \tag{23}$$

where $\dot{\varepsilon}^p_{eq} = \sqrt{(2/3)\dot{\varepsilon}^p_{ij}\dot{\varepsilon}^p_{ij}}$ represents the equivalent plastic strain rate, the plastic flow resistance σ_{flow} is equivalent to the function of τ_y as given by Equation (8), and m is

the rate-dependent sensitivity exponent. For a spherically-symmetric problem, the equilibrium equation is given by

$$\frac{d\dot{\sigma}_r}{dr} + \frac{2}{r}(\dot{\sigma}_r - \dot{\sigma}_\theta) = 0. \tag{24}$$

Using deformation rate V_r to express the strain rate, we have

$$\dot{\varepsilon}_r = \frac{dV_r}{dr}$$
$$\dot{\varepsilon}_\theta = \dot{\varepsilon}_\varphi = \frac{V_r}{r}. \tag{25}$$

There is zero stress boundary in the surface of the particle and zero velocity of deformation along the radial with the radius R, namely

$$\dot{\sigma}_r(r = R) = 0$$
$$V_r(r = 0) = 0, \tag{26}$$

Based on the analytic formulation above, the stress rate can be obtained by Equations (17), (19) and (25), that is

$$\dot{\sigma}_r = \frac{E}{(1+v)(1-2v)}\left[(1-v)\left(\frac{dV_r}{dr} - \dot{\varepsilon}_r^c - \dot{\varepsilon}_r^p\right) + 2v\left(\frac{V_r}{r} - \dot{\varepsilon}_\theta^c - \dot{\varepsilon}_\theta^p\right)\right], \tag{27}$$

$$\dot{\sigma}_r - \dot{\sigma}_\theta = \frac{E}{(1+v)}\left[\frac{dV_r}{dr} - \frac{V_r}{r} - \dot{\varepsilon}_r^c - \dot{\varepsilon}_r^p + \dot{\varepsilon}_\theta^c + \dot{\varepsilon}_\theta^p\right]. \tag{28}$$

2.4. Finite difference method

Combining Equations (9) and (10), the rate dislocation and defect densities can be written as,

$$\frac{d\rho_d}{dt} = \frac{1}{b}\left(\frac{1}{\kappa(\rho_d)^{1/2}} - 2\rho_d y_c\right)|\dot{\varepsilon}^p|, \tag{29}$$

$$\frac{d\rho_f}{dt} = -A_s(\rho_f - \rho_{fs})\frac{d_f}{b}|\dot{\varepsilon}^p|. \tag{30}$$

For given plastic strain rates at time t, Equations (29) and (30) become first-order ordinary differential equations to gain the evolution of dislocation and defect by the finite difference and iterative shooting methods. Thus, Equations (29) and (30) can be rewritten as

$$\frac{d\rho_d}{dt} = \frac{\rho_d^{(i)} - \rho_d^{(i-1)}}{\Delta t}, \tag{31}$$

$$\frac{d\rho_{def}}{dt} = \frac{\rho_{def}^{(i)} - \rho_{def}^{(i-1)}}{\Delta t}. \tag{32}$$

The next node is calculated by iterating. In addition to, the initial defect density ρ_{f0} in Table 1 is used to represent the irradiation degree and the initial value of dislocation is 2.0×10^{-6} nm^{-2} in Table 2 [62]. Similarly, substituting Equations (27) and (28) into Equation (24), the equilibrium equation can be expressed by V_r, that is

$$
\frac{d^2 V_r}{dr^2} + \frac{2}{r}\frac{dV_r}{dr} - \frac{2V_r}{r^2} = \frac{1}{1-v}\frac{d}{dr}[(1-v)(\dot{\varepsilon}_r^c + \dot{\varepsilon}_r^p) + 2v(\dot{\varepsilon}_\theta^c + \dot{\varepsilon}_\theta^p)]
$$
$$
+ \frac{2(1-2v)}{1-v}\frac{1}{r}[(\dot{\varepsilon}_r^c + \dot{\varepsilon}_r^p) - (\dot{\varepsilon}_\theta^c + \dot{\varepsilon}_\theta^p)].
$$
(33)

Once chemical and plastic strain rates are obtained, Equation (33) becomes a second-order ordinary differential equation of V_r. Specifically, the radial distance of a spherical particle is discretized into n points $r^{(i)} \in [0, R]$, ($i = 1, \ldots, n$), with an equal spacing $\Delta r = R / (n-1)$, and then Equation (33) is discretized by

$$
\frac{d^2 V_r}{dr^2} = \frac{V_r^{(i+1)} + V_r^{(i-1)} - 2V_r^{(i)}}{\Delta r^2}, \quad \frac{dV_r}{dr} = \frac{V_r^{(i+1)} + V_r^{(i-1)}}{2\Delta r},
$$
(34)

where V_r^i is the radial velocity at $r^{(i)}$. To determine V_r^i, we can start from $V_r^1(r^1 = 0) = 0$ by the boundary condition of Equation (27), make an initial guess of V_r^2 and solve $V_r^3 \ldots V_r^n$ based on Equations (33) and (34), and then calculate $\dot{\sigma}_r(r = R)$ according to Equation (27). Due to the traction-free boundary condition of Equation (26), the above calculations are repeated to find out an optimal V_r^2, making $\dot{\sigma}_r(r = R)$ approach to zero to update V_r^i at time t. Hence, stress rates at time t are calculated based on Equations (27) and (28), and then the plastic strain rates are updated at time $t + \Delta t$ based on Equations (20–23). For a given chemical strain rate at time $t + \Delta t$, $\dot{c}$ at $t + \Delta t$ is calculated based on a prescribed time step. Further, the above steps can be repeated to determine V_r^i at $t + \Delta t$, accomplishing a loop of numerical integration.

3. Results and discussion

As shown in Figure 4(a), irradiation causes the yield stress increase of metals such as Cu, Fe and Sn. In Figure 4(b), the yield stress increases with neutrons fluence based on the Hall-patch relationship, that is

$$
\sigma_Y = \sigma_0 + a d_g^{-0.5}
$$
(35)

Table 1. Initial defect density and its stabilised value of different radiation conditions [63].

ρ_{f0} (nm^{-2})	ρ_{fs} (nm^{-2})
0	0
1.0×10^{-5}	3.0×10^{-6}
1.0×10^{-4}	3.0×10^{-5}
5.0×10^{-4}	1.5×10^{-5}

Table 2. Model parameters and their detail illustrations for high capacity electrode materials.

Parameter	Definition	Value	Unit	Reference
ν	Poisson's ratio	0.3	–	[63]
E_0	Elastic modulus	51.41	GPa	
m	Strain rate sensitivity	0.01	–	[72]
b	Burgers vector	0.25	nm	[40]
β	Lithiation expansion coefficient	0.26	–	[27]
K	Empirical coefficient	1.15	–	[63]
L	Empirical coefficient	1.47	–	
η	Statistical parameter	32		[62]
ρ_d	Initial dislocation density	2.0×10^{-6}	nm^{-2}	
ξ	Empirical constant	71.43	–	
y_c	Annihilation radius	1	nm	[73]
d_{def}	Critical edge annihilation distance	$2.5(\pm 0.5)$	nm	[63]
d_s	Standoff distance	$1\sim3$	nm	
$\dot{\bar{\varepsilon}}_0^p$	The efficient strain rate constant	0.001	––	[74]
E_f	The defect formation energy	0. 23	eV	[75]

where σ_Y is the yield stress, σ_0 is the lattice frictional stress, a is a constant, and d_g is the grain size. Due to the existence of a large number of irradiated defects, the movement of internal dislocations will be hindered by defects (called irradiation hardening) when the material is subjected to plastic deformation under external loading. For a given strain increment of $d_\varepsilon = 3.0 \times 10^{-6}$, Figure 5 shows the stress–strain curves at different irradiation doses. At the elastic stage, there is almost no influence of irradiation on the stress–strain relations of electrodes, however, the mechanical properties in the plastic stage are completely different: (1) after irradiation, the yield stress rises with increasing the doses, which can be attributed to irradiation hardening because defects impede the dislocation slippage; (2) when irradiation doses exceed a certain value, such as $\rho_{f0} = 1.0 \times 10^{-4}$ nm^{-2}, the flow stress increases initially, and then it drops at the upper yield point. The evolution of flow stress after the yield point is controlled by the competitive mechanism of defect annihilation and dislocation multiplication [40]. On the one hand, the flow stress might decrease because dislocations are unlocked and free to move resulting from the defect annihilation with the
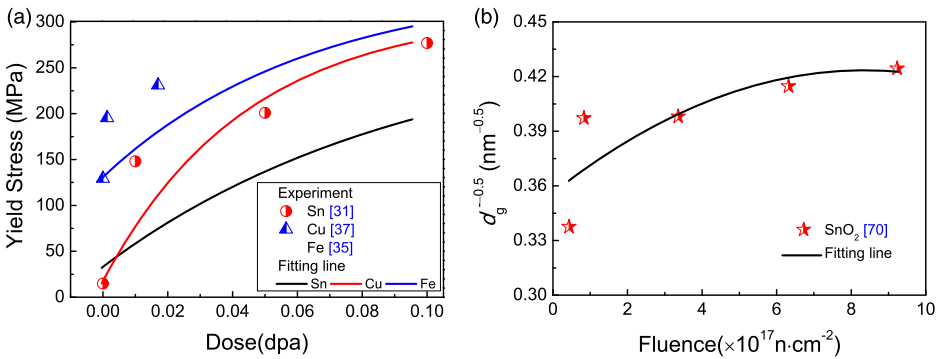
Figure 4. (a) The influence of irradiation dose on the yield stress of Cu, Fe and Sn and (b) the evolution of $d_S^{-0.5}$ for SnO$_2$ film as a function of neutron fluence.
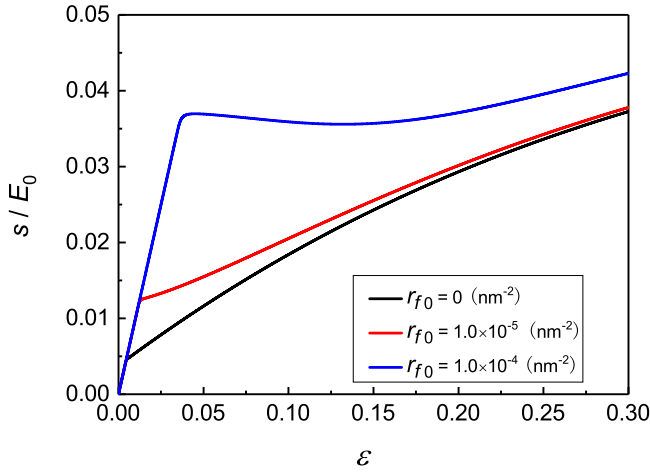
Figure 5. The constitutive relation of uniaxial tension using a constitutive model with different irradiation intensities.

increase of load. On the other hand, the flow stress could increase because of dislocation multiplication. When irradiation dose is large enough, the influence of defect annihilation on flow stress is more than that of dislocation multiplication at the initial phase. Therefore, the flow stress decreases initially due to high defect annihilation but rises with increasing dislocation multiplication.

As shown in Figure 6(a), the Li concentration distribution under three different lithiated states exhibits an obvious feature of sharp concentration transition which separates the Li-poor and Li-rich phase. The corresponding contours show a two-phase boundary moving to the particle centre with increasing lithiation time in Figure 6(b).

The densities of defects and dislocations are affected by irradiation and their interaction in Figure 7. In Figures 7(a–c), at $kt/R = 0.1$, a high-density dislocation appears in a two-phase boundary because the sharp concentration leads to a large misfit strain and dislocations spontaneously nucleate at the interface. Interaction of defects and slip dislocations results in translation of defect type, and further leads to defect annihilation. Thus, near the particle surface, the defect density suddenly decreases. When the initial defect density is 1.0×10^{-5} nm^{-2}, the dislocation density is higher than the defect density in the lithiated region; On the contrary, when the initial defect densities reach to 1.0×10^{-4} nm^{-2} and 5.0×10^{-4} nm^{-2}, the dislocation densities are smaller than that of defects. When the abrupt boundary moves to the particle centre at $kt/R = 0.5$, as shown in Figures 7(d–e) the sharp density boundary has moved toward the centre corresponding to the moving of reaction front. And the dislocation density is still greater than the defect density in the lithiated region. Nevertheless, in Figure 7(f), for $\rho_{f0} = 5.0 \times 10^{-4}$ nm^{-2}, the dislocation density is much lower than the defect density, which limits the degree of dislocation multiplication. Here, it is worth noting that there exists a turning point around 1.0×10^{-4} nm^{-2} in Figures 7(b) and (e), where the densities
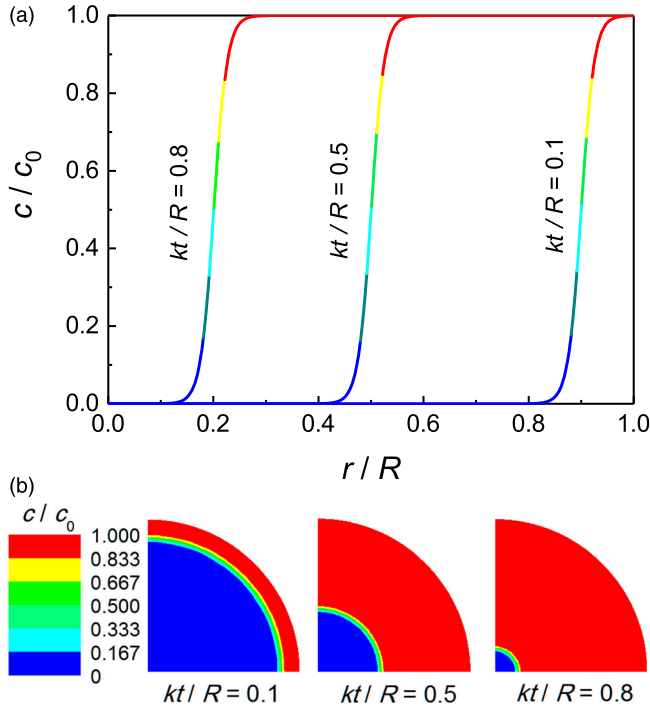
Figure 6. Radial distributions of Li concentration under different lithiated states: (a) the axial concentration graph and (b) the corresponding contour.

of defects and dislocations have an asymptotical phenomenon, reflecting the effect of irradiation on the evolution of microstructures and the fact that the dislocation will be continuously nucleated and absorbed by interface during the reaction.

As shown in Figures 8(a–c), the dislocation density of element A (see Figure 3) rises abruptly with lithiation process, indicating that dislocations readily nucleate at the two-phase boundary and induce local plastic. Finally, the dislocations are absorbed by the moving interaction interface and reached to a stable value. On the other hand, with the increase of irradiation dose, dislocation glide might change the type and number of defects; hence, the defect density decreases with plastic deformation. It is worth mentioning that the change rate of dislocation density decreases with increasing initial defects, and the steady-state values of both dislocation and defect densities exist where their rates are close to zero corresponding to Equations (9) and (11) due to the combined effect of multiplication and annihilation of dislocations. The plastic flow resistance increases with increasing initial defect density at $kt/R = 0.1$ since defects obstruct the glide dislocations, as shown in Figure 9. The plastic flow resistance increases at the lithiated part ($r > 0.8\ R$), which was caused by dislocation activation and multiplication in the case of non-irradiation. However, in the case of $\rho_{f0} > 1.0 \times 10^{-4}\ nm^{-2}$, the plastic flow resistance decreases. Because stress and dislocations contribute to a relatively high annihilation of defects, the effect of annihilation on flow resistance is more than dislocation multiplication.
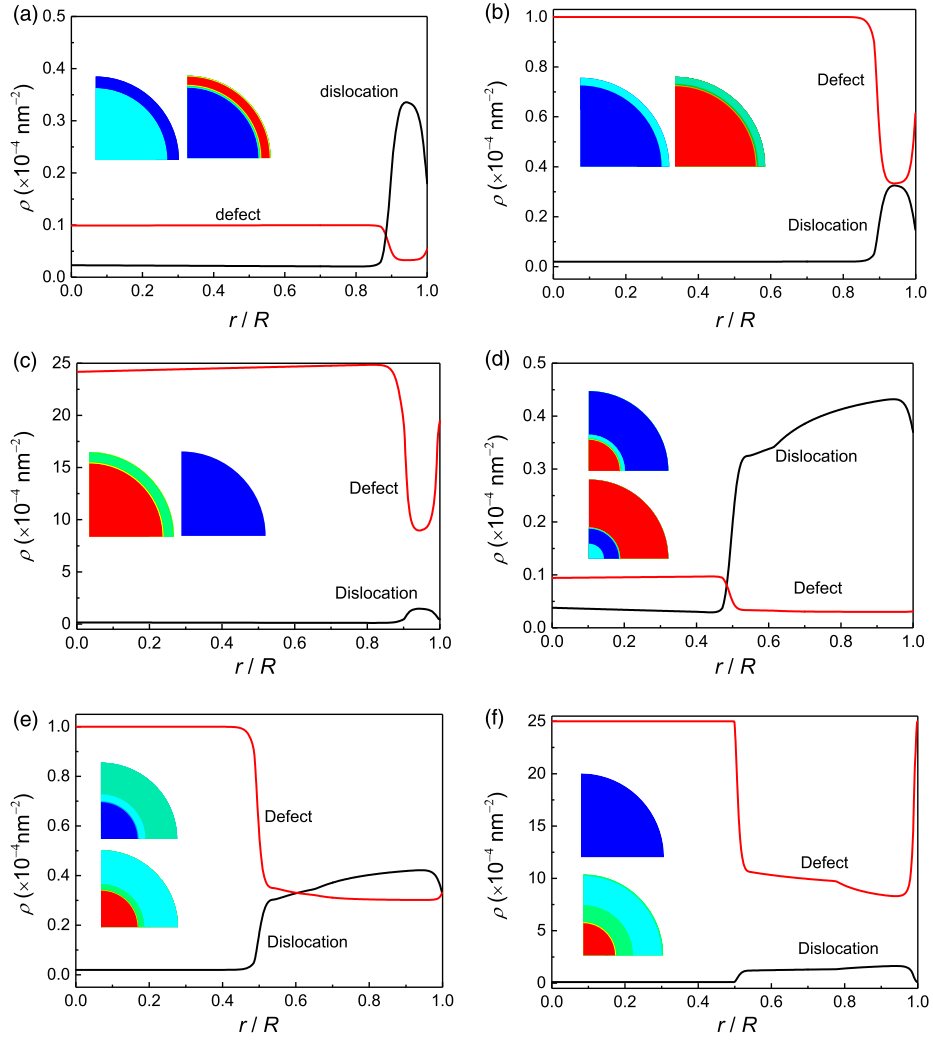
Figure 7. The radial distributions of defect and dislocation densities in a representative irradiation condition that is expressed by the initial defect density during lithiation. (a) $\rho_{fo} = 1.0 \times 10^{-5}$ nm^{-2}, $kt / R = 0.1$, (b) $\rho_{fo} = 1.0 \times 10^{-4}$ nm^{-2}, $kt / R = 0.1$, and (c) $\rho_{fo} = 5.0 \times 10^{-4}$ nm^{-2}, $kt / R = 0.1$, for $kt / R = 0.5$. The irradiation conditions of (d), (e) and (f) correspond to (a), (b) and (c), respectively.

The stress distributions exhibit a very salient feature due to irradiation and lithiation deformation (see Figure 10). There is a sharp stress change at the phase boundary because of the large lithiation strain and plastic yielding and the hoop stress reverses from initial compression (Figures 10(a-c)) to tension (Figures 10(b-d)) in the surface layer. Correspondingly, the unlithiated core suffers a tensile hoop stress and then transfers to hydrostatic compression. This is because the hoop stress is accumulated in the surface layer. After irradiation, the trend of stresses distribution is similar to that of non-irradiation. However, in Figures 10(a-b), the irradiation effect is not very evident because
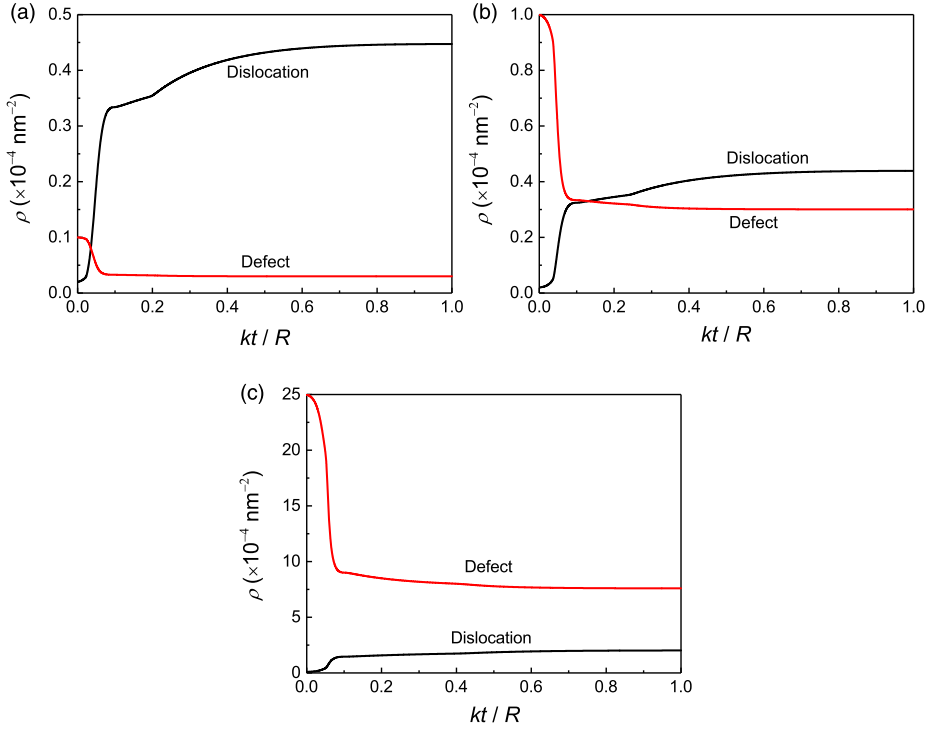
Figure 8. The radical evolution of dislocation and defect densities during lithiation for element A, which is close to the particle surface with different irradiation intensities: (a) $\rho_{fo} = 1.0 \times 10^{-5}$ nm^{-2}, (b) $\rho_{fo} = 1.0 \times 10^{-4}$ nm^{-2} and (c) $\rho_{fo} = 5.0 \times 10^{-4}$ nm^{-2}.

minority defects play a small part in hindering dislocation slip. As seen in Figures 10(c-d), the hoop stress demonstrates an obvious change in the surface layer with increasing the initial defect density by more stress
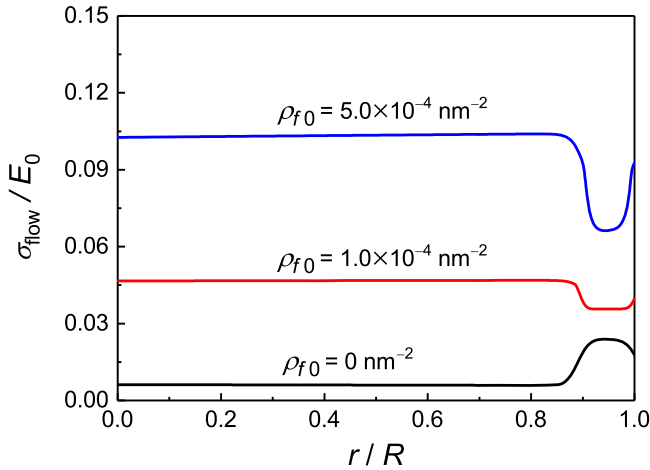

Figure 9. The distribution of yield stress at different initial defect densities and the radial stress distribution is $kt/R = 0.1$.
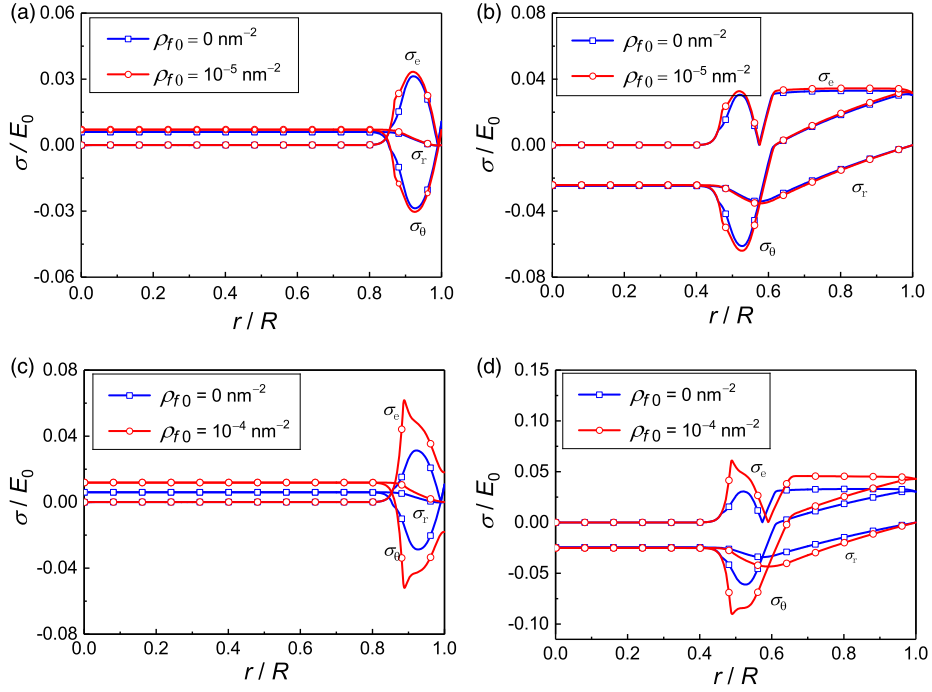
Figure 10. Distributions of radial stress σ_r, hoop stress σ_θ and equivalent stress σ_e at different initial defect densities. (a) and (c) are corresponding to $kt / R = 0.1$, and (b) and (d) refer to $kt / R = 0.5$.

accumulation for the defects distribution to flow stress. Besides, a small sharp peak also appears at the two-phase boundary resulted from the large mismatch stress due to a sharp concentration gradient.

Figure 11. Schematics of the hoop stress experienced by a typical material element A with different initial defect densities.

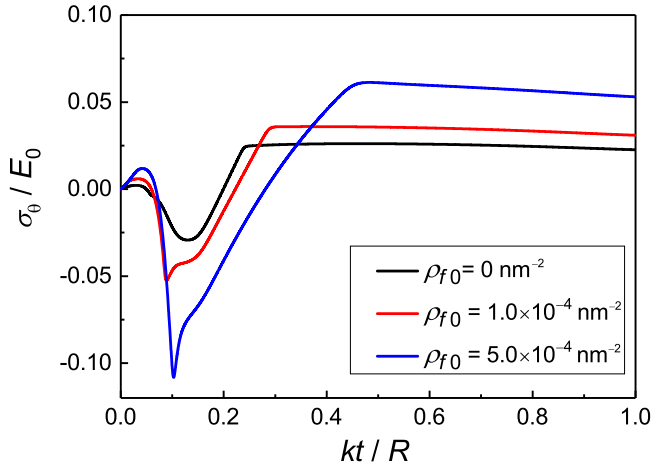To provide a direct physical appreciation of the reversal of hoop compression to tension in the surface layer, we selecting element A (see Figure 3) to probe the effect of irradiation on the hoop stress during Li insertion. As shown in Figure 11, in the unlithiated case, lithiation occurs at the two-phase interface, causing the movement of new reaction along the outward radial direction. This can lead to a radial tensile stress in element A. However, when the reaction front sweeps over the whole element A, local compression stress generates due to the constraint of surrounding materials after a large expansive strain. Finally, the hoop stress reverses from compression to tension since the large lithiation strain and plastic yielding at the front pushes out the material behind it. In the lithiated case, the hoop stress appears a sharp peak when element A is lithiated. As a result, element A experiences compressive elastic unloading, tensile elastic loading and tensile plastic flow. It is worth noting that the tensile plastic flow in the surface layer could cause morphological instability and fracture of electrode particles during Li insertion. The hoop stress increases with raising the initial defect density at the final stage, which was caused by the impediment of defects to dislocation glides and the increase of plastic flow resistance.

Considering the irradiated-defects on the moving rate of reaction front, Figure 12(a) shows that the defects can improve the concentration-dependent lithiation rate, from the initial $k_0 = 1$ to $k > 3$, and then the rate decreases because the interaction between dislocations and defects leads to the vanish of defects during the Li insertion. Furthermore, Figure 12(b) shows the contribution from the stress to the free energy during lithiation. Clearly, it is a linear increase in accordance with the elastic deformation stage; afterwards, ΔG_{stress} increases gently due to the plastic flow; and finally, ΔG_{stress} shows a huge increase.
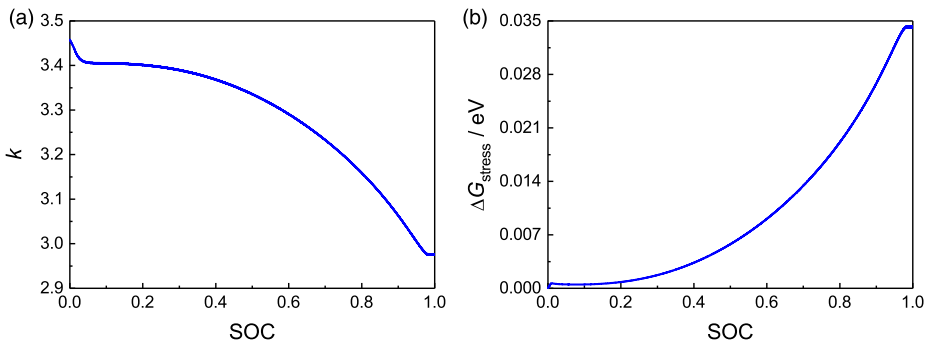

Figure 12. (a) The rate of reaction front and (b) the stress-induced energy barrier for lithiation reaction.

4. Conclusions

In this paper, an electrochemical-irradiated model is developed to explore the interaction between the electrochemical reaction dislocations and irradiation defects on the stress evolution during a two-phase lithiation process. The results indicate that irradiation has an influence on the evolution of stress and the rate of the lithiation reaction front. Especially, when irradiation dose increases during Li intercalation, the initial yield stress rises owing to irradiation hardening through hindering of defects to dislocations. The plastic flow resistance increases obviously with increasing irradiation dose that is attributed by dislocation multiplication. As irradiation continues and the external load increases to a certain level, defects are obliterated or destroyed, the resistance to dislocation slippage decreases, which leads to a reduction of the external load driving dislocation slip and decrease of plastic flow resistance. Furthermore, the hoop tensile stress in the surface layer of the electrode particle rises as irradiation dose increases, which amplifies morphological instability and implies an easier fracture of electrode particles during Li insertion. Last but not least, the defects can improve the rate of lithiation reaction front because that the empty space generated by defect facilitates local rearrangement of atoms to readily accept Li insertion, and the stresses retard lithiation.

However, there are still more factors to be taken into account in this model such as spatial characteristics, temperature and microstructures. It is expected that such a study can be helpful to the understanding of the micro-mechanism of lithiation deformation and applied to study the relationship of mechanical behaviours and electrochemical performance of electrodes in an unconventional environment. We believe that it provides a new way for the development of high-performance LIBs.

Disclosure statement

No potential conflict of interest was reported by the authors.

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